

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCXH16245FT

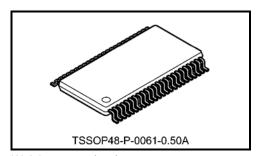
Low-Voltage 16-Bit Bus Transceiver with Bushold

The TC74VCXH16245FT is a high-performance CMOS 16-bit bus transceiver. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This 16-bit bus transceiver is controlled by direction control (DIR) inputs and output enable ($\overline{\text{OE}}$) inputs which are common to each byte. It can be used as two 8-bit transceivers or one 16-bit transceiver. The direction of data transmission is determined by the level of the DIR inputs. The $\overline{\text{OE}}$ inputs can be used to disable the device so that the busses are effectively isolated.

The A, B data inputs include active bushold circuitry, eliminating the need for external pull-up resisisors to hold unused or floating data inputs at a valid logic level.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25 g (typ.)

Features (Note)

- Low-voltage operation: VCC = 1.8 to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation: tpd = 2.5 ns (max) (VCC = 3.0 to 3.6 V)

: tpd = 3.0 ns (max) (VCC = 2.3 to 2.7 V)

: tpd = 5.0 ns (max) (VCC = 1.8 V)

- 3.6-V tolerant control inputs
- Output current : IOH/IOL = ±24 mA (min) (VCC = 3.0 V)

: $IOH/IOL = \pm 18 \text{ mA (min) (VCC} = 2.3 \text{ V)}$

: $IOH/IOL = \pm 6 \text{ mA (min) (VCC} = 1.8 \text{ V)}$

- Latch-up performance: -300 mA
- ESD performance: Machine model ≥ ±200 V

Human body model ≥ ±2000 V

Package: TSSOP

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

Start of commercial production 2000-08

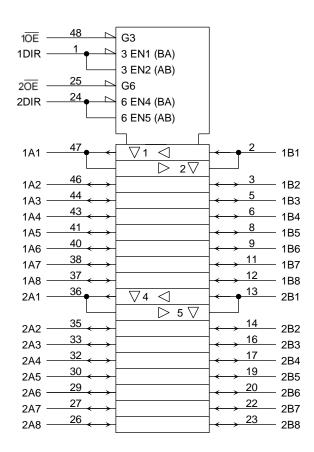
2018-08-21



Pin Assignment (top view)

1DIR 10E 48 1B1 2 1A1 1B2 3 1A2 GND 4 **GND** 45 1B3 5 1A3 1B4 6 1A4 43 Vcc 7 42 Vcc 1B5 8 1A5 1B6 9 1A6 GND 10 39 **GND** 1B7 11 38 1A7 1B8 12 1A8 2B1 13 36 2A1 2B2 14 35 2A2 GND 15 GND 34 2B3 16 33 2A3 2B4 17 2A4 32 V_CC 18 Vcc 2B5 19 30 2A5 2B6 20 29 2A6 GND 21 GND 28 2B7 22 2A7 2B8 23 2A8 26 2OE 2DIR 24 25

IEC Logic Symbol





Truth Table

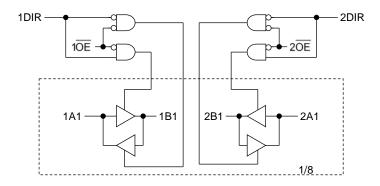
Inp	uts	Fun		
1OE	1DIR	Bus 1A1-1A8	Bus 1B1-1B8	Outputs
L	L	Output	Input	A = B
L	Н	Input	Output	B = A
Н	Х	2	Z	

Inp	uts	Fun		
2 OE	2DIR	Bus 2A1-2A8	Bus 2B1-2B8	Outputs
L	L	Output	Input	A = B
L	Н	Input Output		B=A
Н	Х	2	Z	

X: Don't care

Z: High impedance

System Diagram





Absolute Maximum Ratings (Note 1)

Characteris	Characteristics		Rating	Unit
Power supply voltage		Vcc	-0.5 to 4.6	V
	(DIR, OE)		-0.5 to 4.6	
DC input voltage	(An, Bn)	VIN	-0.5 to $V_{CC} + 0.5$ (Note 2)	V
DC output voltage	(An, Bn)	Vout	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	•	lıK	-50	mA
Output diode current		lok	±50 (Note 4)	mA
Output current		lout	±50	mA
Power dissipation		PD	400	mW
DC V _{CC} /ground current per supply pin		I _{CC} /I _{GND}	±100	mA
Storage temperature		T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: VOUT < GND, VOUT > VCC

Operating Ranges (Note 1) (Note 2)

Characteris	Characteristics		Rating	Unit
Dower aupply voltage		Vcc	1.8 to 3.6	V
Power supply voltage		VCC	1.2 to 3.6 (Note 3)	V
Input voltage	(DIR, OE)	VIN	-0.3 to 3.6	V
iliput voltage	(An, Bn)	V IN	0 to Vcc (Note 4)	V
Output voltage	(An, Bn) Vout		0 to V _{CC} (Note 5)	V
			±24 (Note 6)	
Output current		IOH/IOL	±18 (Note 7)	mA
			±6 (Note 8)	
Operating temperature		T _{opr}	-40 to 85	°C
Input rise and fall time		dt/dv	0 to 10 (Note 9)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either VCC or GND. Please connect both bus inputs and the bus outputs with VCC or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

Note 2: Floating or unused control inputs must be held high or low.

Note 3: Data retention only

Note 4: OFF state

Note 5: High or low state Note 6: VCC = 3.0 to 3.6 V

Note 7: VCC = 2.3 to 2.7 V

Note 8: VCC = 1.8 V

Note 9: VIN = 0.8 to 2.0 V, VCC = 3.0 V



Electrical Characteristics

DC Characteristics (Ta = -40 to 85° C, 2.7 V < V_{CC} ≤ 3.6 V)

Characterist	ics	Symbol	Test C	Condition	V _{CC} (V)	Min	Max	Unit					
	H-level	VIH		_	2.7 to 3.6	2.0	_						
Input voltage	L-level	VIL		_	2.7 to 3.6	_	0.8	V					
				I _{OH} = -100 μA	2.7 to 3.6	V _C C - 0.2							
	H-level	Voн	VIN = VIH or VIL	I _{OH} = -12 mA	2.7	2.2	_						
				I _{OH} = -18 mA	3.0	2.4							
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V					
				I _O L = 100 μA	2.7 to 3.6	_	0.2						
	I laval	\/a-	VIN = VIH or VIL	VIN = VIH or VIL	VIN = VIH or VIL	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$	VIN = VIH or VIL	I _{OL} = 12 mA	2.7	_	0.4	
	L-level	Vol								I _{OL} = 18 mA	3.0	_	0.4
				I _{OL} = 24 mA	3.0	_	0.55						
Input leakage current (DIR, OE)		I _{IN}	V _{IN} = 0 to 3.6 V		2.7 to 3.6	_	±5.0	μА					
Bushold input minimun	n drive hold	1	VIN = 0.8 V		3.0	75		^					
current		II (HOLD)	V _{IN} = 2.0 V		3.0	-75	_	μΑ					
Bushold input over-driv	e current to	current to . V _{IN} = "L"→"H"		V _{IN} = "L"→"H"		_	450	^					
change state (Note)		II (OD)	V _{IN} = "H"→"L"		3.6	_	-450	μА					
3-state output OFF sta	te current	loz	VIN = VIH or VIL VOUT = VCC or GND		2.7 to 3.6	_	±10.0	μА					
Quiescent supply curre	ent	Icc	VIN = VCC or GND		2.7 to 3.6		20.0	μΑ					
Increase in I _{CC} per inp	ut	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		750	μА					

Note: It is a necessary electric current to change the input in "L" or "H".



DC Characteristics (Ta = -40 to 85° C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteris	tics	Symbol	Test Condition		Vcc (V)	Min	Max	Unit
	H-level	VIH		_	2.3 to 2.7	1.6	_	
Input voltage	L-level	VIL		_	2.3 to 2.7	_	0.7	V
				I _{OH} = -100 μA	2.3 to 2.7	V _C C - 0.2	_	
	H-level	Voн	VIN = VIH or VIL	I _{OH} = -6 mA	2.3	2.0	_	
				I _{OH} = -12 mA	2.3	1.8	_	
Output voltage			lo	I _{OH} = -18 mA	2.3	1.7	_	V
			VIN = VIH or VIL	I _{OL} = 100 μA	2.3 to 2.7	_	0.2	
	L-level	VoL		$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 12 mA	2.3	_	0.4
				I _{OL} = 18 mA	2.3	_	0.6	
Input leakage current (DIR, OE)		I _{IN}	V _{IN} = 0 to 3.6 V		2.3 to 2.7	_	±5.0	μА
Bushold input minimu	m drive hold		V _{IN} = 0.7 V		2.3	45	_	^
current			V _{IN} = 1.6 V		2.3	-45	_	μΑ
Bushold input over-drive current to change state (Note)		1	V _{IN} = "L"→"H"		2.7	_	300	^
		lı (OD)	V _{IN} = "H"→"L"		2.7	_	-300	μΑ
3-state output OFF st	ate current	loz	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND		2.3 to 2.7	_	±10.0	μА
Quiescent supply cur	rent	Icc	V _{IN} = V _{CC} or GND		2.3 to 2.7	_	20.0	μА

Note: It is a necessary electric current to change the input in "L" or "H".



DC Characteristics (Ta = -40 to 85° C, $1.8 \text{ V} \le \text{V}_{CC} < 2.3 \text{ V}$)

Characteristi	cs	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
lanut valta sa	H-level	VIH		_	1.8 to 2.3	0.7 × VCC	_	V
Input voltage	L-level	VIL		_	1.8 to 2.3	_	0.2 × VCC	V
	H-level	Voн	V _{IN} = V _{IH} or V _{IL}	V _{IN} = V _{II} or V _{II}		V _C C - 0.2	_	
Output voltage		0		IOH = -6 mA	1.8	1.4	_	V
	L-level	Voi	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	IOL = 100 μA	1.8	_	0.2	
	L-ievei	VoL	$V_{IN} = V_{IH} \text{ or } V_{IL}$	IOL = 6 mA	1.8	_	0.3	
Input leakage current (DIR, $\overline{\text{OE}}$)		lın	V _{IN} = 0 to 3.6 V		1.8	_	±5.0	μΑ
Bushold input minimum	n drive hold	1	VIN = 0.36 V		1.8	25	_	^
current		II (HOLD)	V _{IN} = 1.26 V		1.8	-25	_	μА
Bushold input over-drive current to		li (ann)	V _{IN} = "L"→"H"		1.8	_	200	^
change state (Note)			1.8	_	-200	μА		
3-state output OFF sta	te current	loz	VIN = VIH or VIL VOUT = VCC or GND		1.8	_	±10.0	μА
Quiescent supply curre	ent	Icc	VIN = VCC or GND		1.8	_	20.0	μА

Note: It is a necessary electric current to change the input in "L" or "H".

AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500~\Omega$) (Note 1)

Characteristics	Symbol	Test Condition		Min	Max	Unit
Characteristics	Symbol	rest Condition	Vcc (V)	IVIII I	IVIAX	Offic
			1.8	1.5	5.0	
Propagation delay time	t _{pLH} t _{pHL}	Figure 1, Figure 2	2.5 ± 0.2	1.0	3.0	ns
	PITE		3.3 ± 0.3	8.0	2.5	
			1.8	1.5	7.5	
3-state output enable time	t _{pZL} t _{pZH}	Triquie 1, riquie 3	2.5 ± 0.2	1.0	4.9	ns
			3.3 ± 0.3	0.8	3.8	
			1.8	1.5	5.5	
3-state output disable time	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	2.5 ± 0.2	1.0	4.2	ns
	φηΖ		3.3 ± 0.3	0.8	3.7	
			1.8	_	0.5	
Output to output skew	t _{osLH} t _{osHL}	(Note 2)	2.5 ± 0.2	_	0.5	ns
	108∏L		3.3 ± 0.3	_	0.5	

Note 1: For $CL = 50 \ pF$, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design. (tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)

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Dynamic Switching Characteristics (Ta = 25° C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition	1		Тур.	Unit
Characteristics	Cymbol	rest condition		V _{CC} (V)	ıyρ.	Offic
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (N	lote)	1.8	0.25	
Quiet output maximum dynamic V _{OL}	VOLP	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (N	lote)	2.5	0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (N	lote)	3.3	8.0	
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (N	lote)	1.8	-0.25	
Quiet output minimum dynamic VoL	Volv	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (N	lote)	2.5	-0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (N	lote)	3.3	-0.8	
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (N	lote)	1.8	1.5	
Quiet output minimum dynamic VOH	Vонv	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (N	lote)	2.5	1.9	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (N	lote)	3.3	2.2	

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Ch anastavistica	Complete	Test Condition		T	l lait
Characteristics	Symbol	rest Condition	Vcc (V)	Тур.	Unit
Input capacitance	CIN	_	1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C _{I/O}	_	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Not	9) 1.8, 2.5, 3.3	20	pF

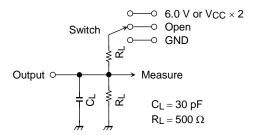
Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·fIN + ICC/16 (per bit)



AC Test Circuit



Parameter	Switch		
t _{pLH} , t _{pHL}	Open		
t _{PLZ} , t _{PZL}	6.0 V V _{CC} × 2	@V _{CC} = 3.3 ± 0.3 V @V _{CC} = 2.5 ± 0.2 V @V _{CC} = 1.8 V	
t _{pHZ} , t _{pZH}	GND		

Figure 1

AC Waveform

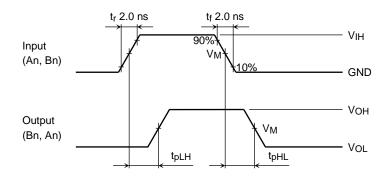


Figure 2 t_{pLH}, t_{pHL}

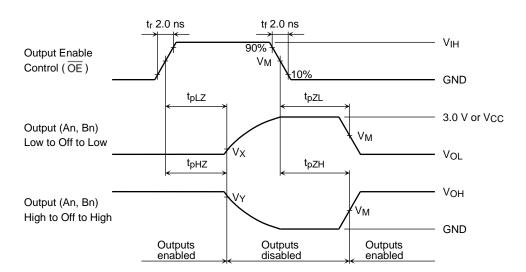


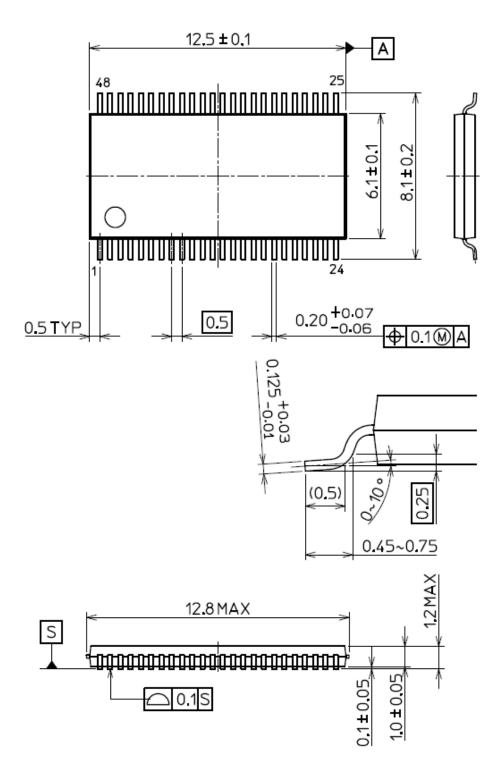
Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Cumbal		Vcc	
Symbol	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2~\textrm{V}$	1.8 V
VIH	2.7 V	Vcc	Vcc
VM	1.5 V	Vcc/2	Vcc/2
Vx	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V
VY	VoH – 0.3 V	VoH – 0.15 V	Voн – 0.15 V



Package Dimensions

TSSOP48-P-0061-0.50A Unit: mm



Weight: 0.25 g (typ.)



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